

NTE5638 TRIAC – 8A Isolated Tab

Description:

The NTE5638 is an 8 Amp TRIAC in a TO220 type package designed to be driven directly with IC and MOS devices and features proprietary, void-free glass passivated chips.

This device is a bi-directional triode thyristor and may be switched from off-state to conduction for either polarity of applied voltage with positive or negative gate trigger current. The NTE5638 is designed for control applications in lighting, heating, cooling and static switching relays.

Absolute Maximum Ratings:

Repetitive Peak Off-State Voltage (Gate Open, $T_J = +110^{\circ}\text{C}$), V_{DRM} 400V
 RMS On-State Current ($T_C = +80^{\circ}\text{C}$, Conduction Angle of 360°C), $I_{\text{T(RMS)}}$ 8A
 Peak Surge (Non-Repetitive) On-State Current (One Cycle, 50Hz or 60Hz), I_{TSM} 80A
 Peak Gate-Trigger Current ($3\mu\text{s}$ Max), I_{GTM} 2A
 Peak Gate-Power Dissipation ($I_{\text{GT}} \leq I_{\text{GTM}}$ for $3\mu\text{s}$ Max), P_{GM} 20W
 Average Gate-Power Dissipation, $P_{\text{G(AV)}}$ 200mW
 Operating Temperature Range, T_J -40° to $+150^{\circ}\text{C}$
 Storage Temperature Range, T_{stg} -40° to $+110^{\circ}\text{C}$
 Typical Thermal Resistance, Junction-to-Case, R_{thJC} 2.5°C/W

Electrical Characteristics: ($T_C = +25^{\circ}\text{C}$, Maximum Ratings unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Peak Off-State Current	I_{DRM}	$V_{\text{DRM}} = 400\text{V}$, Gate Open, $T_J = +110^{\circ}\text{C}$	–	–	0.5	mA
Max. On-State Voltage	V_{TM}	$I_{\text{T}} = 8\text{A}$	–	–	1.6	V
DC Holding Current	I_{H}	Gate Open	–	–	25	mA
Critical Rate-of-Rise of Off-State Voltage	Critical dv/dt	$V_{\text{D}} = 400\text{V}$, Gate Open, $T_C = +100^{\circ}\text{C}$	–	30	–	V/ μs
Critical Rate-of-Rise of Commutation Voltage	Commutation dv/dt	$V_{\text{D}} = 400\text{V}$, $I_{\text{T}} = 8\text{A}$, Gate Unenergized, $T_C = +80^{\circ}\text{C}$	–	2	–	V/ μs
DC Gate Trigger Current T_2 (+) Gate (+), T_2 (–) Gate (–) T_2 (+) Gate (–), T_2 (–) Gate (+)	I_{GT}	$V_{\text{D}} = 12\text{V}$, $R_{\text{L}} = 60\Omega$	–	–	10	mA

Electrical Characteristics (Cont'd): ($T_C = +25^{\circ}\text{C}$, Maximum Ratings unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
DC Gate Trigger Voltage	V_{GT}	$V_D = 12\text{V}$, $R_L = 60\Omega$	–	–	2.2	V
Gate–Controlled Turn–On Time	t_{gt}	$V_D = 400\text{V}$, $I_{GT} = 80\text{mA}$, $t_r = 0.1\mu\text{s}$, $i_T = 10\text{A (Peak)}$	–	2.2	–	μs

